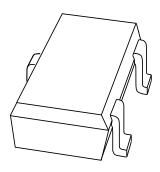
## DISCRETE SEMICONDUCTORS

# DATA SHEET



## BAP64-06W Silicon PIN diode

Product specification Supersedes data of 2001 Feb 02 2001 Apr 17



## Silicon PIN diode BAP64-06W

## **FEATURES**

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Low series inductance
- For applications up to 3 GHz.

## **APPLICATIONS**

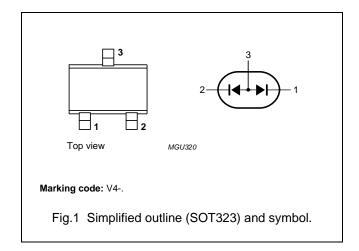
• RF attenuators and switches.

## **DESCRIPTION**

Two planar PIN diodes in common anode configuration in a SOT323 small SMD plastic package.

## **PINNING**

PIN	DESCRIPTION
1	cathode 1
2	cathode 2
3	common connection



## **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V <sub>R</sub>	continuous reverse voltage		_	100	V
IF	continuous forward current		_	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>s</sub> = 90 °C	_	240	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

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## **ELECTRICAL CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	PARAMETER CONDITIONS			UNIT		
Per diode							
V <sub>F</sub>	forward voltage	vard voltage I <sub>F</sub> = 50 mA					
I <sub>R</sub>	reverse current	V <sub>R</sub> = 100 V	_	10	μА		
		V <sub>R</sub> = 20 V	_	1	μΑ		
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 0; f = 1 MHz	0.52	_	pF		
		V <sub>R</sub> = 1 V; f = 1 MHz	0.37	_	pF		
		V <sub>R</sub> = 20 V; f = 1 MHz	0.23	0.35	pF		
r <sub>D</sub>	diode forward resistance	I <sub>F</sub> = 0.5 mA; f = 100 MHz; note 1	20	40	Ω		
		I <sub>F</sub> = 1 mA; f = 100 MHz; note 1	10	20	Ω		
		I <sub>F</sub> = 10 mA; f = 100 MHz; note 1	2	3.8	Ω		
		I <sub>F</sub> = 100 mA; f = 100 MHz; note 1	0.7	1.35	Ω		
$ s_{21} ^2$	isolation	V <sub>R</sub> = 0; f = 900 MHz	18.5	_	dB		
		V <sub>R</sub> = 0; f = 1800 MHz	13.5	_	dB		
		V <sub>R</sub> = 0; f = 2450 MHz	10.9	_	dB		
$ s_{21} ^2$	insertion loss	I <sub>F</sub> = 0.5 mA; f = 900 MHz	1.86	_	dB		
		I <sub>F</sub> = 0.5 mA; f = 1800 MHz	2.06	_	dB		
		I <sub>F</sub> = 0.5 mA; f = 2450 MHz	2.23	_	dB		
$ s_{21} ^2$	insertion loss	I <sub>F</sub> = 1 mA; f = 900 MHz	1.01	_	dB		
		I <sub>F</sub> = 1 mA; f = 1800 MHz	1.06	_	dB		
		I <sub>F</sub> = 1 mA; f = 2450 MHz	1.10	_	dB		
$ s_{21} ^2$	insertion loss	I <sub>F</sub> = 10 mA; f = 900 MHz	0.19	_	dB		
		I <sub>F</sub> = 10 mA; f = 1800 MHz	0.21	_	dB		
		I <sub>F</sub> = 10 mA; f = 2450 MHz	0.27	_	dB		
$ s_{21} ^2$	insertion loss	I <sub>F</sub> = 100 mA; f = 900 MHz	0.08	_	dB		
		I <sub>F</sub> = 100 mA; f = 1800 MHz	0.10	_	dB		
		I <sub>F</sub> = 100 mA; f = 2450 MHz	0.16	_	dB		
τ∟	charge carrier life time	when switched from $I_F$ = 10 mA to $I_R$ = 6 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 3 mA	1.55	-	μs		
L <sub>S</sub>	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	1.6		nH		

## Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	250	K/W

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#### **GRAPHICAL DATA**

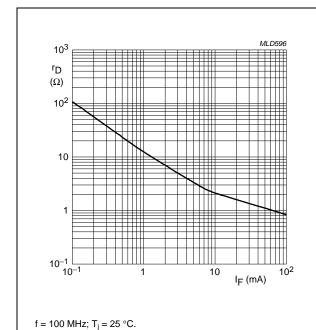


Fig.2 Forward resistance as a function of forward current; typical values.

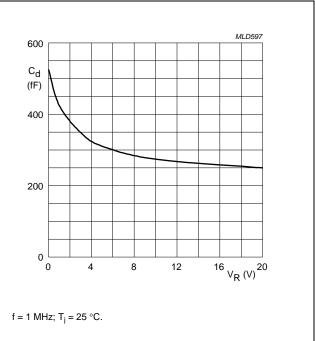
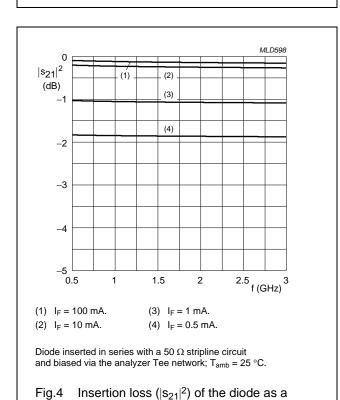
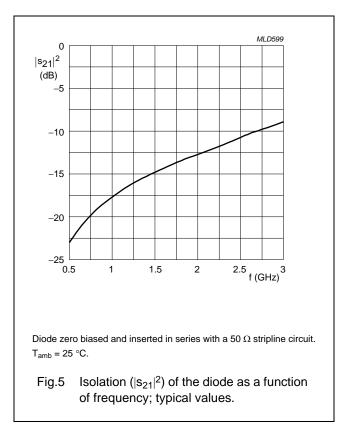


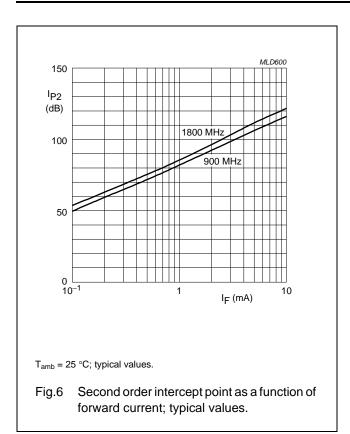
Fig.3 Diode capacitance as a function of reverse voltage; typical values.



function of frequency; typical values.



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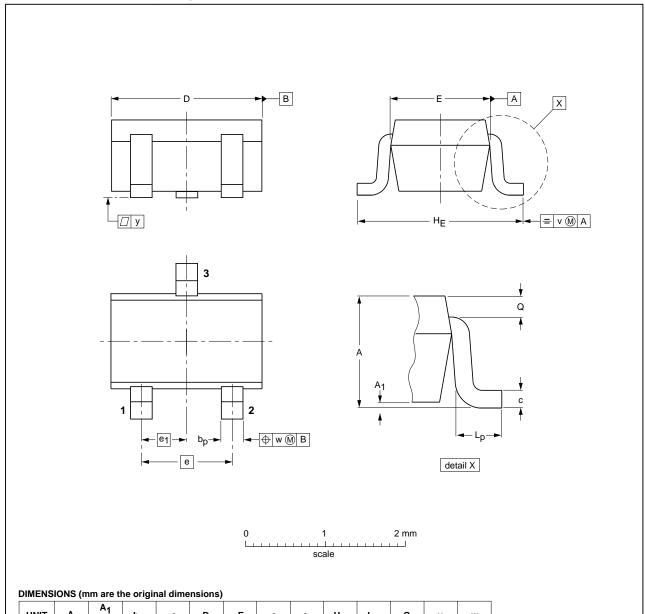


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## **PACKAGE OUTLINE**

## Plastic surface-mounted package; 3 leads

**SOT323** 



UNIT	Α	max	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	V	w	
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2	

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION IEC JEDEC		JEITA	JEITA		ISSUE DATE	
SOT323			SC-70			<del>-04-11-04</del> 06-03-16

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#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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2001 Apr 17

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#### **Customer notification**

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## **Contact information**

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